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Isothermal section of the Ho-Fe-Ga ternary system at 773 K

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ABSTRACT

The isothermal section of the Ho–Fe–Ga ternary phase diagram at 773 K was constructed based on X-ray powder diffraction analysis. Fourteen binary compounds and twelve ternary compounds have been confirmed: Ho₂Fe₁₇ Ho₆Fe₂₃, HoFe₃, HoFe₂, HoGa₃, HoGa₂, Ho₃Ga₅, HoGa, Ho₃Ga₂, Ho₅Ga₃, Fe₃Ga, Fe₆Ga₅, Fe₃Ga₄, FeGa₃, κ_1 -HoFe_{6.02–5.24}Ga_{5.98–6.76}, κ_2 -HoFe_{4.98–4.59}Ga_{7.02–7.41}, κ_3 -HoFe_{17–14.07}Ga_{0–2.93}, κ_4 -HoFe_{13.39–8.45}Ga_{3.61–8.55}, κ_5 -Ho₂FeGa₈, κ_6 -HoFe_{2-2.52}Ga_{0–0.48}, κ_7 -HoFe_{2.36–1.91}Ga_{0.64–1.09}, κ_8 -Ho₂FeGa₈, κ_9 -HoFe_{2-1.46}Ga_{0–0.54}, κ_{10} -HoFe_{1.28–1.16}Ga_{0.72–0.84}, κ_{11} -HoFe_{0.43–0.34}Ga_{1.57–1.66}, and κ_{12} -HoFe_{0.26–0.19}Ga_{1.74–1.81}. The maximum solid solubilities of Ga in HoFe₂, HoFe₃ and Ho₂Fe₁₇ were determined to be 18.1, 11.9 and 15.4 at.%, respectively. The structures of the ternary compounds were refined by Rietveld refinement method. It was shown that all the solid solutions in the ternary system are formed by random distribution of Ga and Fe on the transition metal sites.

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1. Introduction

Element substitution of rare earth (R) or transition metal (T) in R-T compounds is one of the effective ways to improve the magnetic properties of materials [1]. Owing to the unique interactions of gallium with the R and T atoms in R-T alloys, the crystal structure, Curie temperature and other magnetic properties of R-T-Ga compounds depend strongly on the gallium concentration. For example, the Curie temperatures (T_c) of $R_2Fe_{17-x}Ga_x$ (R=Y, SmGd, Tb, Ho and Tm) varied significantly with the Ga concentration [2]. Systematic studies showed that the phase relations and structural characteristics of $R_2Fe_{17-x}Ga_x$ (R=Rare earth) compounds depend strongly on the Ga content. With increasing Ga content, a structural transformation from the hexagonal Th₂Ni₁₇-type structure to the rhombohedral Th₂Zn₁₇-type structure was observed in $R_2Fe_{17-x}Ga_x$. The Curie temperature of the compound increased firstly with the Ga concentration, reached a maximum value and then decreased. The exchange interaction in $R_2Fe_{17-x}Ga_x$ with different Ga concentration varied between Fe atoms, but almost unchanged between R atom and Fe atom [3]. In addition, the compounds $RFe_{12-x}Ga_x$ derived from the ThMn₁₂-type structure, such as RFe₆Ga₆, can be stabilized by the addition of Ga to the R-Fe binary

The phase diagrams of the Ho-Co-Ga, Sm-Co-Ga, Er-Fe-Ga and Sc-Fe-Ga ternary systems show that there are rich ternary compounds with various structures in R-Co (Fe)-Ga ternary systems [5]. However, there are also some inconsistent reports on

the stability of the compounds and the phase relations of the systems involving gallium. For Ho-Ga binary system, two binary compounds Ho₃Ga₂ (Gd₃Ga₂ -type) [6] and Ho₃Ga₅ (Tm₃Ga₅ -type) [7] was reported, but the Ho₃Ga₂ was not shown while the Ho₃Ga₅ was speculative drawn with dot line in the Ho-Ga phase diagram in Ref. [8]. Although the isothermal section of the Ho-Fe-Ga ternary system at 870 K has been reported by Raghavan [9], there still exists some unreasonable issues regarding the existence of the compounds and phase boundaries. For instance, it is unreasonable for the coexistence of the solid solution of HoFe_{0.1-0.2}Ga_{2.9-2.8} (τ_4) and the compound HoGa₃ with the same cubic AuCu₃- type structure (S.G, Pm-3m) at the same temperature. The compounds R₄FeGa₁₂ (R=Y, Er, Ho, Dy and Tb), with a cubic $U_4Fe_6Ga_7$ -type structure, in some R-Fe-Ga system were reported recently [9,10], but the compound Ho₄FeGa₁₂ was not shown in the isothermal section at 870 K reported by Raghavan et al. [9]. Therefore, the structure and the composition of Ho(Fe,Ga)₃(τ_4) warrants a further confirmation. In addition, it was reported that the structure of R(Fe,Ga)₁₂ (R = Gd, Tb) [11,12] compound transformed from ThMn₁₂-type structure (S.G. I4/mmm) to ScFe₆Ga₆-type structure (Immm) with the decrease of the gallium content at 773 K, whereas the ScFe₆Ga₆ type structure of HoFe_{5.9}Ga_{6.1} compound was stable up to 1073 K [13]. However, the isothermal section of Ho-Fe-Ga at 870 K showed that the $HoFe_{12-x}Ga_x$ crystallized in the ThMn₁₂-type structure within the whole homogeneity range without any change in structure. A series of isothermal sections at 773 K of R-Fe-Ga tenary system, such as Tb-Fe-Ga [11], Nd-Fe-Ga [14] and Gd-Fe-Ga [12], have been determined by our group. In the Ho-Fe-Ga system, the compounds Ho₂FeGa₈ and Ho₄FeGa₁₂ are heavy fermion materials. Constructing the isothermal section of Ho-Fe-Ga at 773 K will be helpful for exploring new ternary compounds, designing novel magnetic func-

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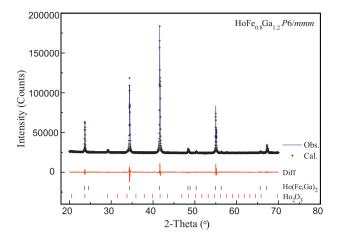


Fig. 1. XRD Rietveld refinement result of the compound HoFe_{0.2}Ga_{1.8} at 773 K.

tional materials, and for crystal growth of the compounds, etc. It also helps to answer the questions mentioned above.

2. Experimental procedure

Polycrystalline Ho–Fe–Ga alloys were prepared by arc melting technique using a non-consumable tungsten electrode and a water-cooled copper tray in pure argon atmosphere. The holmium, iron and gallium metals with purity higher than 99.9% were used as starting materials. Titanium was used as an oxygen getter during the melting process. The alloys were re-melted at least three times to ensure complete fusion and composition homogeneity. The melted buttons were sealed in evacuated quartz tubes, in which titanium chips were placed as an oxygen getter, and then put in a resistance furnace for homogenization annealing. The homogenization annealing was performed at 1123 K for 20 days for the Fe-rich alloys with Ho less than 20 at.% and Ga less than 55 at.%, while at 873 K for 20 days for other alloys. The alloys were cooled from their homogenization temperatures to 773 K, and then kept at 773 K for 5 days followed by quenching in liquid nitrogen. About 170 samples in total were prepared in this work. X-ray powder diffraction (XRD) data were col-

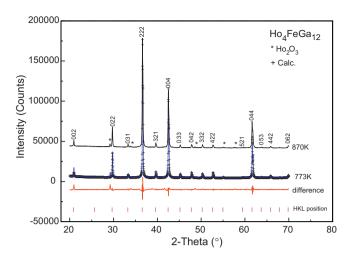


Fig. 3. XRD Rietveld refinement result of the compound Ho₄FeGa₁₂.

lected by a Bruker D8 Advance SS/18 kW diffractometer with CuK α radiation. JADE 5.0 and Topas 3.0 software were used for phase analysis and structure refinement.

3. Results and discussion

3.1. Phase analysis

X-ray diffraction analysis in the present study confirmed the existence of fourteen binary compounds in the Ho–Fe–Ga ternary system at 773 K, which is in good agreement with the reports on the related binary phase diagrams in Ref. [8] except for the Ho₃Ga₂ and Ho₃Ga₅ in Ho–Ga binary system. The XRD pattern of the alloy with composition of Ho₅4Ga₄₆ (in at.%) consists of the patterns of Ho₃Ga₂, HoGa and a small amount of Ho₂O₃, instead of those for Ho₅Ga₃ and HoGa phases. The trace amount of Ho₂O₃ may be formed by active Ho and the trace of O₂ during heat treatment,

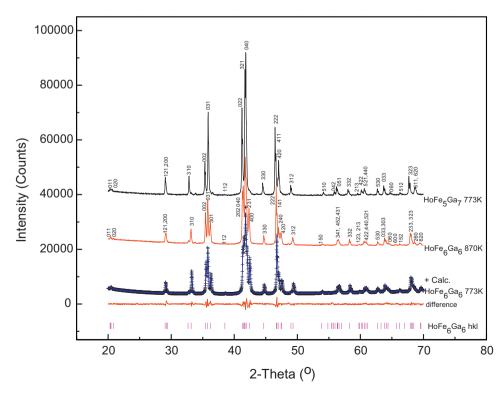


Fig. 2. XRD Rietveld refinement result of the compounds of $HoFe_{12-x}Ga_x$.

Table 1Crystallographic data of the elements and the compounds in the Ho–Fe–Ga ternary system at 773 K.

Phase	Ga (at.%)	Space group	Structure type	Lattice parameters (nm)			Reference
				a	b	С	
Но		P6 ₃ /mmc	Mg	0.3609		0.5697	[9]
α-Fe		Im 3 m	W	0.2932			[9]
Ga		Стса	Ga	0.4520	0.7660	0.4526	[9]
HoFe ₂		Fd3m	$MgCu_2$	0.73			[9]
Ho ₆ Fe ₂₃		Fm3m	Th_6Mn_{23}	1.2032			[9]
Ho ₅ Ga ₃		P4/nnc	Si ₃ Ba ₅	0.7586		1.4001	[9]
Ho ₃ Ga ₂		I4/mcm	Gd_3Ga_2	1.1489		1.470	[9]
				1.150(2)		1.4766(3)	This work
HoGa		Cmcm	CrB	0.433	1.09	0.409	[9]
Ho₃Ga₅		pnma	Tm₃Ga₅	1.1347	0.9630	0.6046	[9]
				1.1370(6)	0.96093(6)	0.60517(4)	This work
HoGa ₂		P6/mmm	AlB_2	0.4281		0.4042	[9]
HoGa ₃		Pm3̄m	AuCu ₃	0.4235			[9]
Fe₃Ga		Pm3̄m	AuCu ₃	0.3679			[9]
Fe ₆ Ga ₅		C2/m	Fe ₆ Ge ₅	1.0058	0.7946	0.7747	[9]
				β = 109.33°			
Fe ₃ Ga ₄		C2/m	Fe ₃ Ga ₄	1.0091	0.7666	0.7866	[9]
				β = 106.67°			
FeGa ₃		P4 ₂ /mnm	FeGa ₃	0.6263		0.6556	[9]
κ ₁ -HoFe _{6.02-5.24} Ga _{5.98-6.76}	46.0-52.0	Immm	ScFe ₆ Ga ₆	0.5060	0.8521	0.8644	[9]
				0.5049-0.5076	0.8541-0.8577	0.8624-0.8658	This work
κ ₂ -HoFe _{4.98-4.59} Ga _{7.02-7.41}	54.0-57.0	I4/mmm	ThMn ₁₂	0.8570		0.5053	[5]
				0.8643-0.8667		0.5087-0.5091	This work
κ_3 -Ho ₂ Fe _{17-14.07} Ga _{0-2.93}	0-15.4	P6 ₃ /mmc	Th ₂ Ni ₁₇	0.8458-0.8547		0.8285-0.8348	This work
κ_4 -Ho ₂ Fe _{13.39-8.45} Ga _{3.61-8.55}	19.5-45.0	R3m	Th_2Zn_{17}	0.8787		1.2604	[16]
				0.8555-0.8781		1.2538-1.2607	This work
κ ₅ -Ho ₂ FeGa ₈		P4/mmm	Ho ₂ CoGa ₈	0.4226		1.1088	[9]
				0.4230		1.1085	This work
κ_6 -HoFe _{3-2.52} Ga _{0-0.48}	0-11.9	R3m	NbBe ₃	0.5110-0.5146		2.453-2.468	This work
κ_7 -HoFe _{2.36-1.91} Ga _{0.64-1.09}	16.0-27.3	P6 ₃ /mmc	CeNi ₃	0.5154-0.5195		1.6679-1.6532	This work
κ ₈ -Ho ₄ FeGa ₁₂	70.5-72.5	Im3m	U ₄ Fe ₆ Ga ₇	0.8510-0.8518			This work
κ_9 -HoFe _{2-1.46} Ga _{0-0.54}	0-18.1	Fd3m	$MgCu_2$	0.7317-0.7411			This work
κ ₁₀ -HoFe _{1.28-1.16} Ga _{0.72-0.84}	24.0-28.0	P6 ₃ /mmc	$MgZn_2$	0.5297-0.5274		0.8628-0.8640	This work
κ ₁₁ -HoFe _{0.43-0.34} Ga _{1.57-1.66}	52.5-55.5	Imma	CeCu ₂	0.4356-0.4354	0.7045-07024	0.7602-0.7611	This work
κ_{12} -HoFe _{0.26-0.19} Ga _{1.74-1.81}	58.0-60.5	P6/mmm	AlB_2	0.4344-0.4356		0.3626-0.3593	This work

leading to small deviation of the composition of the sample from the nominal one, which has very limited effect on the analysis of the phases and phase relationship in the Ho–Fe–Ga ternary system. Therefore, the compound ${\rm Ho_3Ga_2}$ should be a stable one under our experimental conditions. In the same way, the alloy ${\rm Ho_{42}Ga_{58}}$ is found to be composed of HoGa, ${\rm Ho_3Ga_5}$ and ${\rm Ho_2O_3}$ phases. Thus, the existence of ${\rm Ho_3Ga_5}$ compounds is confirmed. The existence of ${\rm Ho_3Ga_2}$ and ${\rm Ho_3Ga_5}$ was also confirmed at 870 K [9]. The Rietveld refinement results of the XRD patterns of the two alloys mentioned above are included as supplementary information.

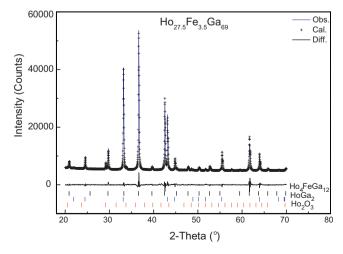


Fig. 4. XRD Rietveld refinement result of the alloy Ho_{27.5}Fe_{3.5}Ga₆₉ at 870 K.

Twelve ternary compounds or solid solutions are identified in the Ho-Fe-Ga ternary system at 773 K: κ_1 -HoFe_{6.02-5.24}Ga_{5.98-6.76}, κ_3 -HoFe_{17-14.07}Ga_{0-2.93}, κ_2 -HoFe_{4.98–4.59}Ga_{7.02–7.41}, $\label{eq:hofe} \text{HoFe}_{13.39-8.45} \quad \text{Ga}_{3.61-8.55}, \quad \kappa_5\text{-Ho}_2\text{FeGa}_8, \quad \kappa_6\text{-HoFe}_{3-2.52}\text{Ga}_{0-0.48},$ κ_7 -HoFe_{2.36-1.91}Ga_{0.64-1.09}, κ_8 -Ho₄FeGa₁₂, κ_9 -HoFe_{2-1.46} Ga_{0-0.54}, $\kappa_{10}\text{-HoFe}_{1.28-1.16}\text{Ga}_{0.72-0.84}\text{, }\kappa_{11}\text{-HoFe}_{0.43-0.34}\text{Ga}_{1.57-1.66}\text{ and }\kappa_{12}\text{-}$ $HoFe_{0.26-0.19}Ga_{1.74-1.81}$. The crystal structural types, composition ranges, and lattice parameters of the compounds and solid solution are listed in Table 1. The structural parameters of ternary compounds, except for the well known solid solutions Ho₂Fe_{17-x}Ga_x (κ_3) , HoFe_{3-x}Ga_x (κ_6) and HoFe_{2-x}Ga_x (κ_9) , derived from Rietveld refinements are listed in Table 2. The ternary compound $HoFe_{0.26-0.19}Ga_{1.74-1.81}(\kappa_{12})$ was also reported to be stable at 870 K [9] but its structure type was not given. The results of Rietveld refinement (Fig. 1) indicate that κ_{12} has an AlB₂-type structure with space group P6/mmm, the same as HoGa₂. It is interesting to note that solubility of iron in $HoGa_2$ is negligibly small, whereas the homogeneity range is about 6.2-8.7 at.% Fe in κ_{12} , but they have same hexagonal $AlB_2\mbox{-type}$ structure. The lattice of κ_{12} expands in a and b directions and shrinks in c direction comparing to that of $HoGa_2$ to ensure structural stability. The a/c ratio of κ_{12} and HoGa2 is about 1.20, and 1.06, respectively. In comparison to the isothermal section at 870 K [9], some salient difference is observed in the isothermal section at 773 K. The solid solution phase $HoFe_{12-x}Ga_x$ at 773 K crystallizes in the $ScFe_6Ga_6$ -type structure (Immm) for x = 5.98 - 6.76 and in the ThMn₁₂-type structure (S.G. I4/mmm) for x = 7.02 - 7.41 (Fig. 2), while it crystallized in the ThMn₁₂-type structure in the whole homogeneity range (x=5.9-6.9) at 870 K [9]. Our experimental results also reveal that the structure of Ho(Fe,Ga)₁₂ transformed from ThMn₁₂-type

Table 2Refined cell and atomic parameters for nine ternary compounds.

Phase	Atom	Site	X	у	Z	Occ
κ_1 -HoFe ₆ Ga ₆ S.G. Immm, ScFe ₆ Ga ₆ -type, a = 5.0590(5) Å, b = 8.5218(8) Å, b = 8.6749(5) Å, $R_{\rm exp}$ = 0.9%, $R_{\rm wp}$ = 1.81%, $R_{\rm B}$ = 0.278%	Но	2a	0	0	0	1
	Ga1 Fe1	4e 4f	0.3354(7) 0.2591(9)	0 1/2	0 0	1 1
	Ga2	41 4g	0.2591(9)	0.3425(8)	0	1
	Ga2 Ga3	4g 4h	0	0.8111(8)	1/2	1
	Fe3	8k	1/4	1/4	1/4	1
κ_2 -HoFe _{4.84} Ga _{7.16} S.G. <i>I4/mmm</i> , ThMn ₁₂ -type, a = 8.6436(4) Å, c = 5.0879(3) Å, $R_{\rm exp}$ = 5.34%, $R_{\rm wp}$ = 13.75%, $R_{\rm B}$ = 3.66%	Но	2a	0	0	0	1
CAP WP J B	Fe _{0.78} Ga _{0.32}	8f	1/4	1/4	1/4	1
	Fe _{0.15} Ga _{0.85}	8i	0.6607(4)	0	0	1
	Fe _{0.38} Ga _{0.62}	8j	0.2856(4)	1/2	0	1
κ_4 -Ho ₂ Fe ₉ Ga ₈ S.G. $R\bar{3}m$, Th ₂ Zn ₁₇ -type, a = 8.7555(2)Å, c = 12.5597(3)Å, $R_{\rm exp}$ = 0.97%, $R_{\rm wp}$ = 2.08%, $R_{\rm B}$ = 0.35%	Но	6c	0	0	0.3498(5)	1
	Fe	6c	0	0	0.1154(1)	1
	Fe	9d	1/2	0	1/2	1
	Fe _{0.15} Ga _{0.85} Fe _{0.85} Ga _{0.15}	18h 18f	0.3139(9) 0.5	0 0.5	0 0.1571(7)	1 1
$κ_5$ -Ho ₂ FeGa ₈ S.G. $P4/mmm$, Ho ₂ CoGa ₈ -type, a = 4.230(1)Å, c = 10.085(2)Å,	Fe	1a	0	0	0	1
$R_{\text{exp}} = 1.16\%$, $R_{\text{wp}} = 3.58\%$, $R_{\text{B}} = 2.32\%$	Ga1	2e	0	1/2	1/2	1
	Но	2g	0	0	0.3104(4)	1
	Ga2	2h	1/2	1/2	0.2925(7)	1
	Ga3	4i	0	1/2	0.1138(3)	1
κ_7 -HoFe _{2.08} Ga _{0.92} S.G. $P6_3/mmc$, CeNi ₃ -type, a = 5.1799(1) Å, $c = 16.6376(5)$ Å, $R_{\text{exp}} = 0.96\%$, $R_{\text{wp}} = 2.20\%$, $R_{\text{B}} = 0.44\%$	Но	2c	1/3	2/3	1/4	1
	Но	4f	1/3	2/3	0.0375(3)	1
	Fe Co	2a	0	0	0	1
	Fe _{0.48} Ga _{0.52} Fe _{0.62} Ga _{0.38}	2b 2d	0 1/3	0 2/3	1/4 3/4	1 1
	Fe _{0.69} Ga _{0.38}	12k	0.826(1)	0.652(2)	0.1277(4)	1
κ_8 -Ho ₄ FeGa ₁₂ S.G.Im $\overline{3}$ m, U ₄ Fe ₆ Ga ₇ -type, a = 8.5112(3)Å, R _{exp} = 1.22%,	Но	8c	1/4	1/4	1/4	1
$R_{wp} = 5.74\%$, $R_B = 1.21\%$	Fe	2a	0	0	0	1
	Ga	12d	1/4	0	1/2	1
	Ga	12e	0.2799(6)	0	o [']	1
κ_{10} -HoFe _{1.26} Ga _{0.74} S.G. $P6_3/mmc$, MgZn ₂ -type, a = 5.2742(2) Å, c = 8.6284(3) Å, $R_{\rm exp}$ = 1.0%, $R_{\rm wp}$ = 3.8%, $R_{\rm B}$ = 1.77%	Но	4f	1/3	2/3	0.0555(3)	1
Text Tool Tay 5000, The Trivia	Fe _{0.63} Ga _{0.37} Fe _{0.63} Ga _{0.37}	2a 6h	0 0.829(5)	0 0.656(1)	0 1/4	1 1
κ_{11} -HoFe _{0.38} Ga _{1.62} , S.G. Imma, CeCu ₂ -type, a = 4.3549(1) Å, b = 7.0447(2) Å, c = 7.6062(2) Å, R_{exp} = 1.2%, R_{wp} = 6.12%, R_{B} = 4.22%	Но	4e	0	1/4	0.5308(3)	1
Nexp 1.2/0, NWp - 0.12/0, NB - 4.22/0	$Fe_{0.19}Ga_{0.81}$	8h	0	0.0393(5)	0.1680(5)	1
κ ₁₂ -HoFe _{0.2} Ga _{1.8} S.G. <i>P</i> 6/ <i>mmm</i> , AlB ₂ -type, <i>a</i> = 4.34325(8) Å, <i>c</i> = 3.62566(9) Å,	Но	1a	0	0	0	1
$R_{\text{exp}} = 1.29\%, R_{\text{Wp}} = 6.34\%, R_{\text{B}} = 1.81\%$	Fe _{0.1} Ga _{0.9}	2d	1/3	2/3	1/2	1

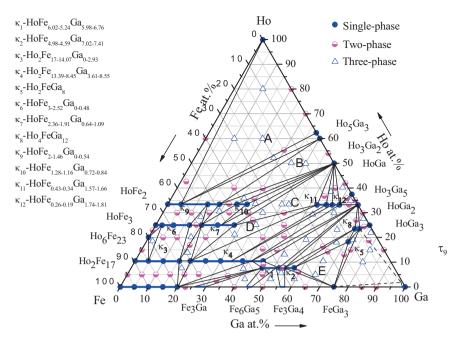


Fig. 5. The isothermal section of the Ho-Fe-Ga ternary system at 773 K.

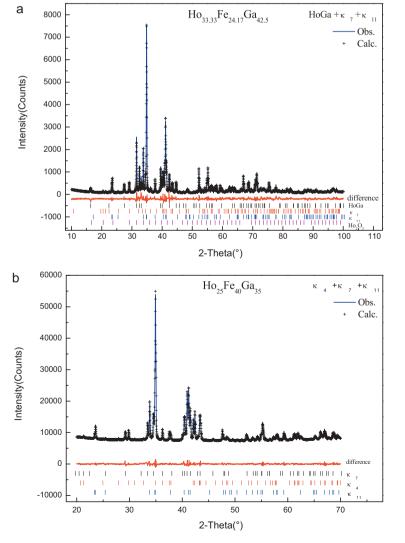


Fig. 6. XRD Rietveld refinement result of the Ho-Fe-Ga alloy. (a): Ho_{33,33}Fe_{24.17}Ga_{42.5} (labeled with C in Fig. 5); (b): Ho₂₅Fe₄₀Ga₃₅ (labeled with D in Fig. 5).

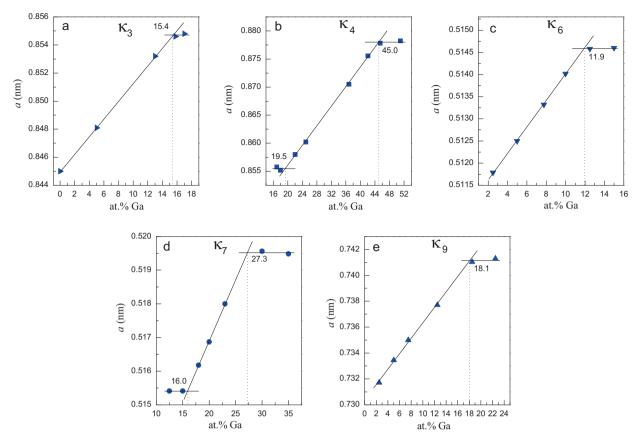


Fig. 7. Variation of the lattice parameter a with Ga content for determination of the solid solubility of Ga in the ternary solid solutions (a: κ₃; b: κ₄; c: κ₆; d: κ₇; e: κ₉).

structure (S.G. I4/mmm) to ScFe₆Ga₆-type structure (Immm) with the decrease of the gallium content at 870K. The compound Ho₄FeGa₁₂ was identified at 773 K (Fig. 3), which crystallized in an cubic U₄Fe₆Ga₇-type structure (S.G. Im-3m) with the lattice parameter almost double that of Ho(Fe,Ga)₃ (τ_4) reported at 870 K. The composition of Ho₄FeGa₁₂ is very close to that of Ho(Fe,Ga)₃ (τ_4) . The XRD pattern of the Ho₄FeGa₁₂ alloy, which was annealed at 870 K and then quenched in liquid nitrogen, manifested that it still holds the U₄Fe₆Ga₇-type structure even at 870 K (Fig. 3). The Rietveld refinement result of the XRD pattern of the alloy $Ho_{27.5}$ $Fe_{3.5}Ga_{70.8}$, which is located in the $HoGa_2 + Ho(Fe,Ga)_3$ (τ_4) two-phase region in the section at 870 K, also showed that the alloy consisted of Ho₄FeGa₁₂ and HoGa₂ with a small amount of Ho₂O₃ impurity at 870 K (Fig. 4). The so-called Ho(Fe,Ga)₃ (τ_4) phase was not observed at both 773 K or 870 K in present work. Unlike HoGa₂ and $Ho(Fe,Ga)_2(\tau_6)$ mentioned above, the existence of $Ho(Fe,Ga)_3$ (τ_4) is questionable, because the iron has no obvious solubility in HoGa₃ and it cannot re-dissolve in HoGa₃ with a larger solubility by adjusting the lattice parameter ratio of a/c in cubic system with the same AuCu₃- type structure. Thus, the so-called Ho(Fe,Ga)₃ (τ_4) should not exist but be replaced by Ho₄FeGa₁₂ at 870 K.

3.2. Isothermal section at 773 K

By comparing and analyzing the XRD patterns of the samples and identifying the phases in each sample, we have constructed the isothermal section of the Ho–Fe–Ga ternary system at 773 K as shown in Fig. 5. It is composed of 26 single-phase regions, 58 two-phase regions and 33 three-phase regions. The X-ray diffraction patterns for some representative alloys located in some three-phase regions are shown in Fig. 6 and as supplementary materials. The alloy ${\rm Ho}_{60}{\rm Fe}_{20}{\rm Ga}_{20}$ (label with A in Fig. 5) was located in the

HoFe₂ +Ho₅Ga₃ +Ho three-phase region; the alloy Ho₅₀Fe₁₀Ga₄₀ (label with B in Fig. 5) was located in the Ho₃Ga₂ +HoGa +HoFe₂ three-phase region; the alloys Ho_{33.33}Fe_{24.17}Ga_{42.5} (label with C in Fig. 5) was located in the HoGa+ κ_7 + κ_{11} three-phase region (Fig. 6a); the alloys Ho₂₅Fe₄₀Ga₃₅ (label with D in Fig. 5) was located in the κ_4 + κ_7 + κ_{11} three-phase region (Fig. 6b); the alloy Ho₅Fe₂₉Ga₆₆ (label with E in Fig. 5) was located in the κ_2 + κ_5 +FeGa₃ three-phase region, respectively.

The homogeneity ranges of the single-phase regions were determined by phase-extinction method (extrapolating I-x curve to I=0) or lattice parameter method (kinks on the composition dependence of lattice parameters). The variation of the lattice parameters of κ_3 , κ_4 , κ_6 , κ_7 and κ_9 with Ga content are shown in Fig. 7(a)–(e), which show that the homogeneity ranges at 773 K are from 19.5 to 45.0 at.% Ga for κ_4 , and from 16.0 to 27.3 at.% Ga for κ_7 , respectively, while the maximum solid solubilities of Ga in κ_3 , κ_6 and κ_9 at 773 K are determined to be 15.4, 11.9, and 18.1 at.% Ga, respectively. Similarly, the homogeneity ranges are from 46 to 52 at.% Ga for κ_1 , 54 to 57 at.% Ga for $\kappa_2, 70.5$ to 72.5 at.% Ga for $\kappa_8, 24.0$ to 28.0 at.% Ga for $\kappa_{10}, 52.5$ to 55.5 at.% Ga for κ_{11} , and 58.0 to 60.5 at.% Ga for κ_{12} , respectively (Table 1). For the Fe-Ga binary system, the homogeneity ranges of the solid solutions are 0–20.0 at.% Ga for α -Fe. 27.0–30.0 at.% Ga for Fe₃Ga,44.5-46.0 at.% Ga for Fe₆Ga₅, 56.5-58.0 at.% Ga for Fe₃Ga₄, respectively, according to the binary Fe-Ga phase diagram [15].

In addition to the difference mention above between the isothermal sections reported for T=870 K [9] and we determined at 773 K, the tie-line between Ho(Fe,Ga) $_2(\tau_8)$ (S.G. $P6_3/mmc$) and Ho(Fe,Ga) $_2(\tau_7)$ (S.G. Imma) reported at 870 K [9] does not exist at 773 K. Instead, the two three-phase regions: HoGa+ τ_7 + τ_8 , τ_7 + τ_8 +Ho(Fe,Ga) $_3(\tau_5)$, and a two-phase region of τ_7 + τ_5 at 870 K changed to two three-phase region of HoGa+ κ_7 + κ_{11} , HoGa+ κ_7 + κ_{10} , and a two-phase region of HoGa+ κ_{10} at 773 K.

4. Conclusion

The isothermal section of the Ho–Fe–Ga ternary system was constructed at 773 K. It consists of 26 single-phase regions, 58 two-phase regions and 33 three-phase regions. There are fourteen binary compounds and twelve ternary compounds at 773 K. The structures of the ternary compounds were refined by Rietveld refinement technique. A new compound, Ho₄FeGa₁₂ is identified and stable up to 870 K. The solid solubilities of all the ternary solid solution phases were determined based upon XRD phase analysis.

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Appendix A. Supplementary data

Supplementary data associated with this article can be found, in the online version, at doi:10.1016/j.jallcom.2010.10.072.

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